



JOR21XD6 Series

Rev.A.1.0

DESCRIPTION:

The products are 6-pin optical relays. The device consists of an AlGaAs infrared emitting diode input stage optically coupled to a high-voltage output detector circuit in a plastic DIP6 package with different lead forming options. The detector consists of a high-speed photovoltaic diode array and driver circuitry. The products are widely used in measuring and testing equipment, security and disaster prevention market, industrial machinery and equipment.

MAIN FEATURES

High isolation 5000 Vrms

Wide variation of load voltage 60V to 600V

Operating temperature range -40°C to 110°C

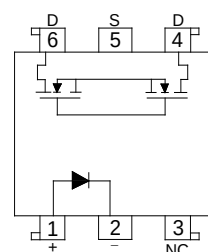
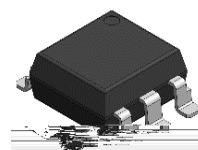
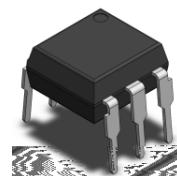
REACH & RoHS compliance

HBM: H3A; MM: M4; CDM: C3

CQC approved

VDE approved

UL approved



ABSOLUTE MAXIMUM RATINGS (Temperature=25°C)

Parameter			Symbol	Value	Unit
Input	Forward Current		I _F	50	mA
	Peak Forward Current		I _{FP}	1	A
	Reverse Voltage		V _R	6	V
	Input Power Dissipation		P _D	75	mW
Output	Load Voltage	JOR212D6	V _O	60	V
		JOR213D6		100	
		JOR214D6		400	
		JOR216D6		600	
	Continuous load current	JOR212D6	I _O	2	A
		JOR213D6		1.25	
		JOR214D6		0.1	
		JOR216D6		0.05	
	Output Power Dissipation		P _O	300	mW
Total Power Dissipation			P _{tot}	375	mW

Isolation Voltage	V_{iso}	5000	Vrms
Operating Temperature	T_{opr}	-40~110	
Junction Temperature	T_j	125	
Storage Temperature	T_{stg}	-40~125	
Soldering Temperature	T_{sol}	260	

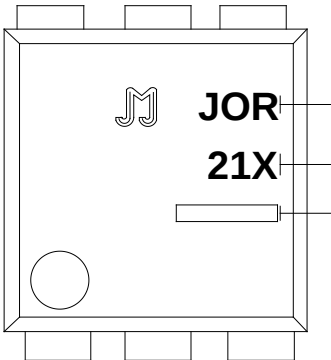
NOTE1: 100Hz

NOTE2:

ELECTRICAL CHARACTERISTICS (Temperature=25°C)

Parameter			Symbol	Condition	Min.	Typ.	Max.	Unit
Input	Forward Voltage		V_F	$I_F=10mA$	-	1.3	1.5	V
	Reverse Current		I_R	$V_R=6V$	-	-	1	μA
	Action Current		$I_{F(ON)}$	$I_O=I_{O(MAX)}$	-	1.5	3	mA
	Reset Current		$I_{F(OFF)}$	$I_O=I_{O(MAX)}$	0.4	0.8	-	mA
Output	On Resistance	JOR212D6	R_{on}	$I_F=5mA$ $I_O=Max.$ Within 1s on time	-	0.05	0.1	Ω
		JOR213D6			-	0.15	0.4	
		JOR214D6			-	20	30	
		JOR216D6			-	30	40	
	Off State Leakage Current		I_{Leak}	$I_F=0mA$, $V_O=Max.$	-	-	1	μA
	Output Capacitance		C_{OFF}	$V_{OFF}=0V$, $f_0=1MHz$	10	-	1000	pF
Switching Characteristics	Isolation Resistance		R_{ISO}	DC500V 40~60%R.H.	10^{12}	-	-	Ω
	Floating Capacitance		C_{IO}	$V=0$, $f=1MHz$	-	0.8	-	pF
	Turn On Time	JOR212D6	t_{on}	$I_F=5mA$, $I_O=Max.$	-	1	2	ms
		JOR213D6			-	0.6	2	
		JOR214D6			-	0.21	0.5	
		JOR216D6			-	0.18	0.5	
	Turn Off Time	JOR212D6	t_{off}	$I_F=5mA$, $I_O=Max.$	-	0.2	1	ms
		JOR213D6			-	0.2	1	
		JOR214D6			-	0.2	1	
		JOR216D6			-	0.2	1	

ORDERING AND MARKING INFORMATION

MARKING INFORMATION			
		: Company Abbr. : Part Number & Rank : Production Information Code	
Packing Quantity			
Option	Quantity	Quantity – Inner box	Quantity –Outer box
DIP			
SMD			

Characteristics Curves

FIG.1: LED Dropout Voltage vs. Ambient Temperature

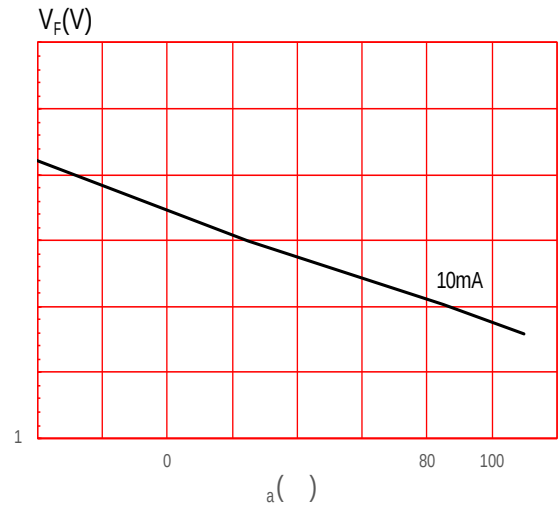
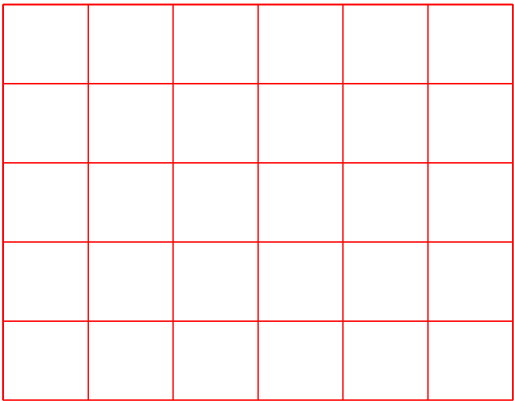
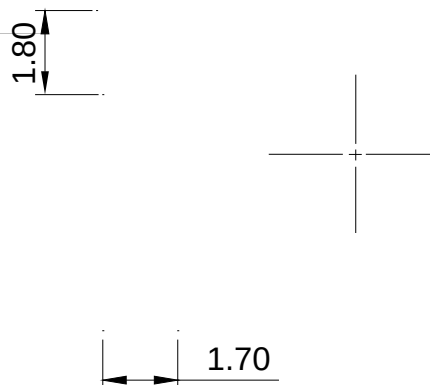


FIG.2: Output Current vs. Output Voltage



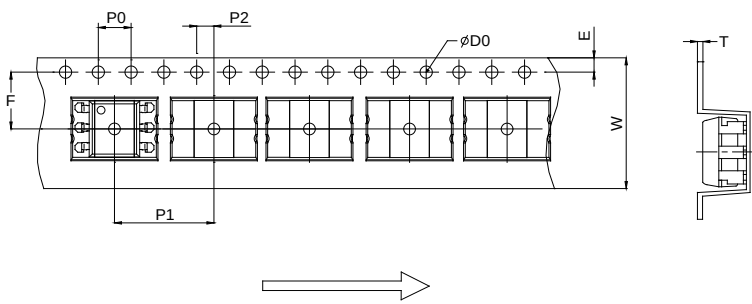
RECOMMENDED SOLDER MASK (Dimensions in mm unless otherwise stated)

Option SMD



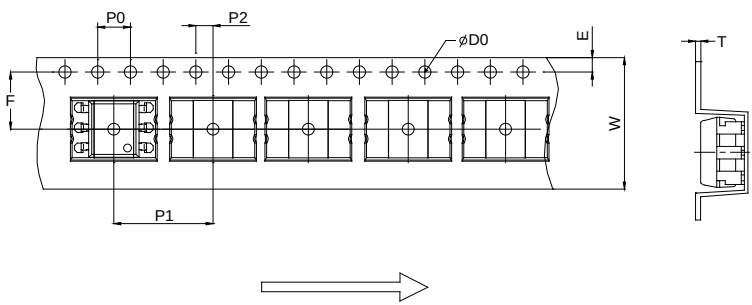
CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option S



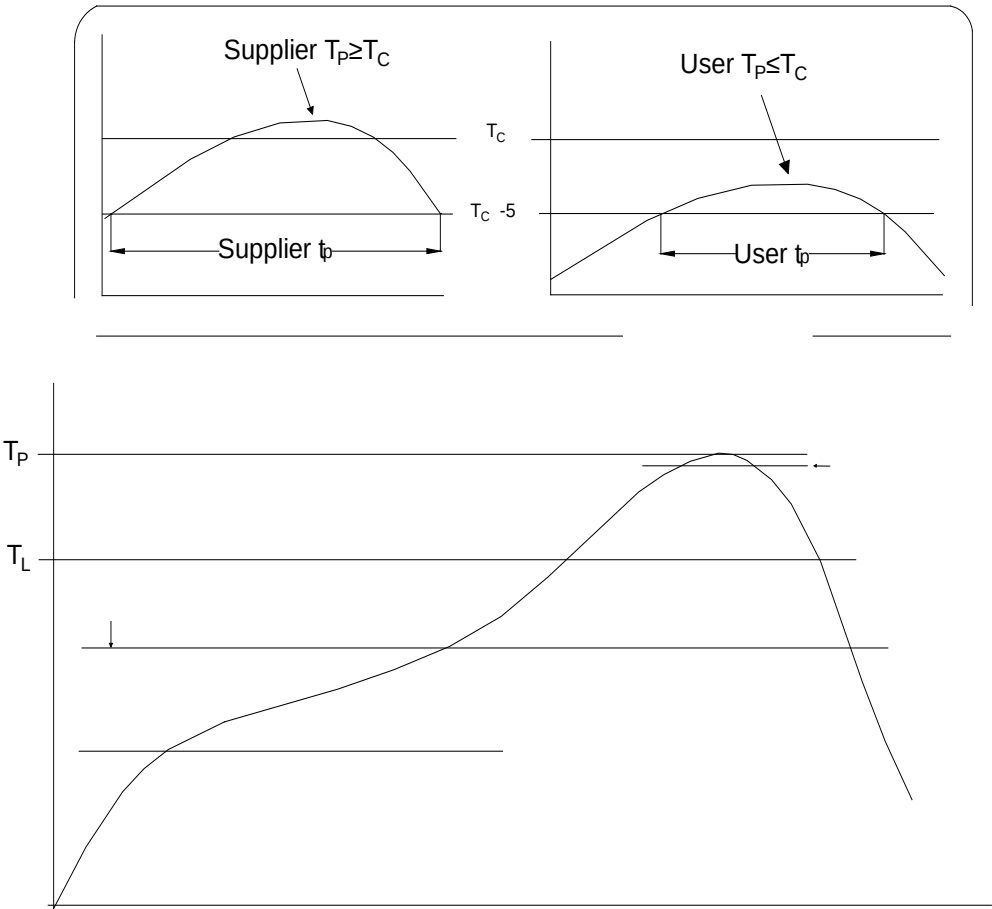
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
D0		1.50	1.60		0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	11.90	12.00	12.10	0.469	0.472	0.476
P2	1.90	2.00	2.10	0.075	0.079	0.083
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
T	0.35	0.40	0.45	0.014	0.016	0.018
W	15.70	16.00	16.30	0.618	0.630	0.642

Option L

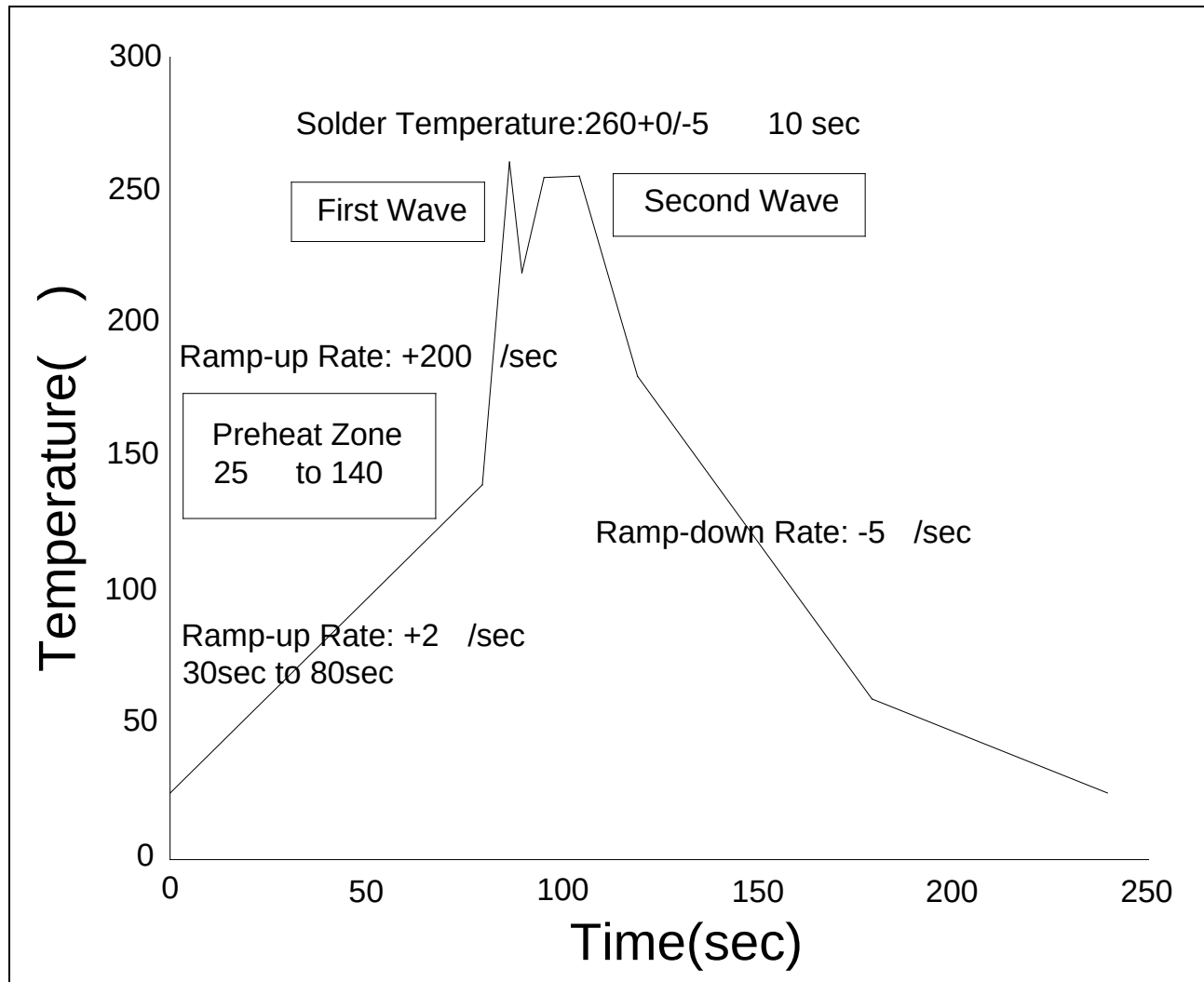


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REFLOW INFORMATION



WAVE SOLDERING



HAND SOLDERING BY SOLDERING IRON

Soldering Temperature	360 ± 5
Soldering Time	3s max.

Note:

1. Reflow soldering is recommended at the temperatures and times shown, no more than three times.
- 2.